

**Application Data Sheet****Application Information**

Application Type:: Regular  
Subject Matter:: Utility  
Title:: Trench MOSFET Having Implanted Drain-Drift Region And Process For Manufacturing The Same  
Attorney Docket Number:: SCX010-5D US  
Request for Early Publication?:: No  
Request for Non-Publication?:: No  
Total Drawing Sheets:: 18  
Small Entity?:: No  
Petition Included?:: No  
Secrecy Order in Parent Appl.?:: No

**Applicant Information**

Applicant Authority Type:: Inventor  
Primary Citizenship Country:: US  
Status:: Full Capacity  
Given Name:: Mohamed  
Middle Name:: N.  
Family Name:: Darwish  
Name Suffix::  
City of Residence:: Campbell  
State or Province of Residence:: California  
Country of Residence:: US  
Street of Mailing Address:: 675 Regas Drive  
City of Mailing Address:: Campbell  
State or Province of Mailing Address:: California  
Country of Mailing Address:: US  
Postal or Zip Code of mailing 95008

address::

**Correspondence Information**

Correspondence Customer Number:: 34036

**Representative Information**

Representative Customer Number::	34036
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**Domestic Priority Information**

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This application	Divisional of	10/317,568	12/12/02
10/317,568	Continuation in part of	09/898,652	07/03/01

**Assignee Information**

Assignee Name:: Siliconix incorporated  
Street of Mailing Address:: 2201 Laurelwood Road  
City of Mailing Address:: Santa Clara  
State of Mailing Address:: California  
Country of Mailing Address:: USA  
Zip Code of Mailing Address:: 95054